TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA7358AP

FM FRONT-END

The TA7358AP is designed for a FM front-end application, which is suitable to a portable radio or a radio cassette.

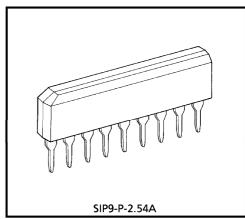
Comparing with conventional types, supply voltage dependence, overload characteristics and spurious radiation characteristics are improved.

FEATURES

• Wide supply voltage range : $V_{CC} = 1.6 \sim 6.0 \text{V}$

Excellent supply voltage dependence of local oscillator

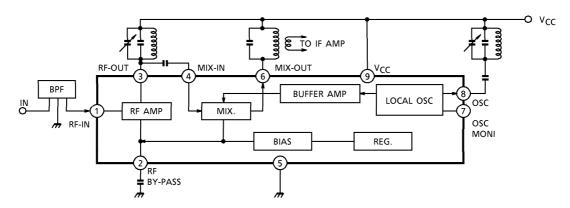
: Oscillation stop $V_{CC} = 0.9V$ (Typ.)



Weight: 0.92g (Typ.)

- Improved inter-modulation characteristics by double balanced type mixer circuit.
- Low spurious radiation.
- Built-in clampping diode for the local oscillator output.

BLOCK DIAGRAM



EXPLANATION OF TERMINALS (Terminal voltage is DC voltage at Ta = 25°C, V_{CC} = 5V, and no signal)

PIN No.	SYMBOL	INTERNAL	TERMINAL VOLTAGE (V)
1	FM-RF IN	3	0.8
2	BY PASS	THE BIAS BIAS	1.5
3	FM-RF OUT	GND (5) 2	5.0
4	MIX IN	© Vcc	1.5
5	GND	_	0
6	MIX OUT	cf. pin ④	5.0
7	OSC MONITOR	Vcc (9)	4.3
8	OSC	7 T GND (5	5.0
9	V _{CC}		5.0

MAXIMUM RATINGS (Ta = 25° C)

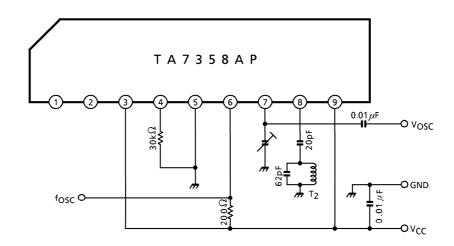
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	8	V
Power Dissipation	P _D (Note)	500	mW
Operating Temperature	T _{opr}	- 25∼75	°C
Storage Temperature	T _{stg}	- 55∼150	°C

(Note) Derated above 25°C in the proportion of $4mW/^{\circ}C$.

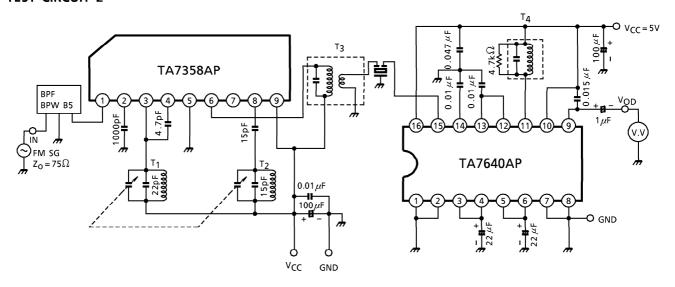
ELECTRICAL CHARACTERISTICS ($V_{CC} = 3V$, f = 83MHz, $f_m = 1kHz$, $\Delta f = \pm 22.5kHz$, $Ta = 25^{\circ}C$)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Curre	Supply Current		2	V _{in} = 0	_	5.2	8.0	mA
-3dB Limiting Sensitivity		V _{in} (lim)	2	_	_	3.0	7.0	dBμV EMF
Quiescent Sensitivity		QS	2	_	_	11.0	_	dBμV EMF
Conversion Gain		GC	_		_	31	_	dB
Local OSC Voltage		Vosc	1	f _{OSC} = 60MHz	90	165	220	mV _{rms}
Pin ① Impedance	Parallel Input Resistance	r _{ip1}	3		_	57	_	Ω
Pin ③ Impedance	Parallel Output Resistance	r _{op3}		f = 83MHz	_	25	_	kΩ
	Parallel Output Capacitance	c _{op3}	3		_	2.0	_	pF
Pin ④ Impedance	Parallel Input Resistance	r _{ip4}			_	2.7	_	kΩ
	Parallel Input Capacitance	c _{ip4}	3		_	3.3	_	pF
Pin ⑥	Parallel Output Resistance	r _{op6}	- 3	(40.7041)	_	100	_	kΩ
Impedance	Parallel Output Capacitance	C _{op6}	3	f = 10.7MHz	_	4.8	_	pF
Local OSC Stop Voltage		V _{stop}	1	_		0.9	1.3	V

TEST CIRCUIT 1



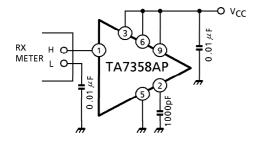
TEST CIRCUIT 2



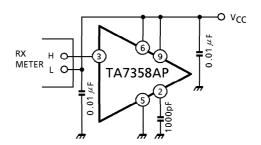
TEST CIRCUIT 3

Input output impedance

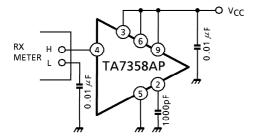
(1) r_{ip1}, c_{ip1}



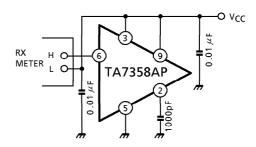
(2) r_{op3} , c_{op3}



(3) r_{ip4}, c_{ip4}



(4) r_{op6}, c_{op6}



TEST CIRCUIT COIL DATA (Japan band for 76.0MHz to 108.0MHz)

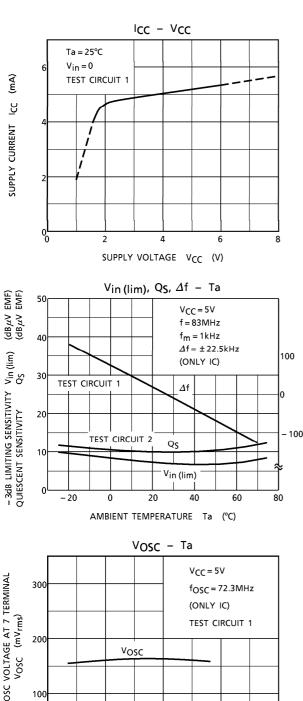
COIL	fo	Qo	TURNS	CAPACITANCE	
T ₁ RF Coil	100MHz	100	0.5mm ϕ 2 $\frac{1}{4}$ T Center Tap (Japan Band)	15pF (External)	FERRITE CORE
T ₂ OSC Coil	100MHz	100	$0.5 \text{mm} \phi$ 2 $\frac{1}{2} \text{ T}$ (Japan Band)	15pF (External)	FERRITE CORE
T ₃ IFT Coil	10.7MHz	115	$\textcircled{1}-\textcircled{3}$ 12T $\textcircled{4}-\textcircled{6}$ 1T Wire 0.12mm ϕ UEW SUMIDA ELECTRIC Co., LTD. 5764 or equivalent	75pF	Pin (BOTTOM VIEW)
T ₄ Quad Coil	10.7MHz	150	4- 6 14T Wire 0.12mm ϕ UEW SUMIDA ELECTRIC Co., LTD. 44M-933A or equivalent	47pF	(BOTTOM VIEW)

Band Pass Filter (BPF)

SOSHIN ELECTRIC Co., LTD. BPWB5

Tuning Cpacitor

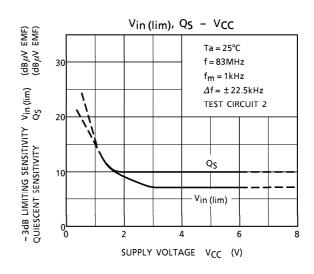
ALPS ELECTRIC Co., LTD. CB41EL933

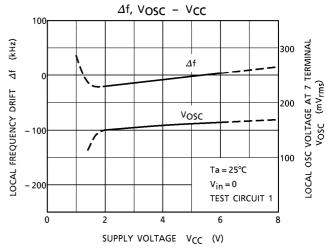


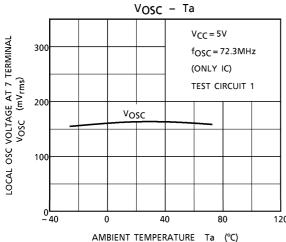
(kHz)

Δf

LOCAL FREQUENCY DRIFT



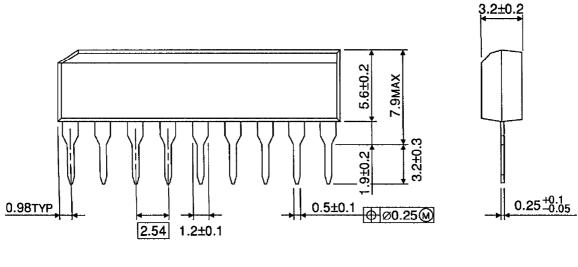


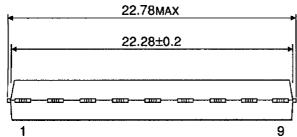


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PACKAGE DIMENSIONS

SIP9-P-2.54A Unit: mm





Weight: 0.92g (Typ.)

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000707EBA

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